

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Euijoon Yoon et al.

Application No.: 10/563,854

Confirmation No.: 3828

Filed: June 9, 2006

Art Unit: 2823

For: GROWTH METHOD FOR NITRIDE
SEMICONDUCTOR EPITAXIAL LAYERS

Examiner: Maldonado, J. J.

AMENDMENT ACCOMPANYING REQUEST FOR CONTINUED EXAMINATION

MS RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

December 8, 2008

Dear Sir:

INTRODUCTORY COMMENTS

This Amendment is submitted concurrently with a Request for Continued Examination (RCE) for the above-identified application.

In response to the Final Office Action dated July 8, 2008 and the mailing of an Advisory Action on October 28, 2008, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.